

LT1783

NOLOGY 1.25MHz, Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amp in SOT-23

reverse supply voltages up to 18V.

below the negative supply.

refer to the LT1782.

The LT[®]1783 is a 1.25MHz op amp available in the small

SOT-23 package that operates on all single and split

supplies with a total voltage of 2.5V to 18V. The amplifier

draws less than 300µA of guiescent current and has

reverse battery protection, drawing negligible current for

The input range of the LT1783 includes ground, and a

unique feature of this device is its Over-The-Top[™] opera-

tion capabilitity with either or both of its inputs above the

positive rail. The inputs handle 18V both differential and

common mode, independent of supply voltage. The input

stage incorporates phase reversal protection to prevent

false outputs from occurring even when the inputs are 9V

The LT1783 can drive loads up to 18mA and still maintain

rail-to-rail capability. A shutdown feature on the 6-lead version can disable the part, making the output high

impedance and reducing guiescent current to 5µA. The

LT1783 op amp is available in the 5- and 6-lead

SOT-23 packages. For applications requiring lower power,

DESCRIPTION

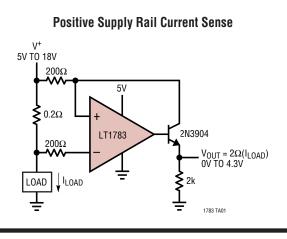
FEATURES

- Operates with Inputs Above V⁺
- Rail-to-Rail Input and Output
- Micropower: 300µA Supply Current Max
- Small SOT-23 Package
- Gain Bandwidth product: 1.25MHz
- Slew Rate: 0.42V/µs
- Low Input Offset Voltage: 800µV Max
- Single Supply Input Range: 0V to 18V
- High Output Current: 18mA Min
- Specified on 3V, 5V and ±5V Supplies
- Output Shutdown on 6-Lead Version
- Reverse Battery Protection to 18V
- High Voltage Gain: 1500V/mV
- Operating Temperature Range: –40°C to 85°C

APPLICATIONS

- Portable Instrumentation
- Battery- or Solar-Powered Systems
- Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- MUX Amplifiers
- 4mA to 20mA Transmitters

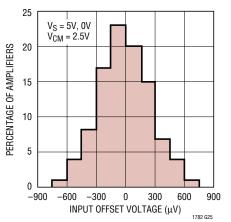
TYPICAL APPLICATION



Distribution of Input Offset Voltage

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Over-The-Top is a trademark of Linear Technology Corporation.



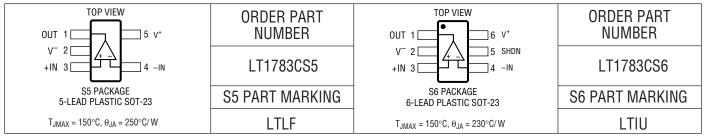
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ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V ⁺ to V ⁻)	18V
Input Differential Voltage	18V
Input Pin Voltage to V ⁻ +24V/-	-10V
Shutdown Pin Voltage Above V ⁻	18V
Shutdown Pin Current ±1	0mA
Output Short-Circuit Duration (Note 2) Inde	finite

Operating Temperature Range (Note 10) –40°C to 85°C
Specified Temperature Range 0°C to 70°C
Junction Temperature 150°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



Consult factory for Industrial and Military grade parts.

ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = 3V, 0V; V_S = 5V, 0V, V_{CM} = V_{OUT} = half supply, for the 6-lead part V_{PIN5} = 0V, pulse power tested unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	$ \begin{array}{l} T_A = 25^{\circ}C \\ 0^{\circ}C \leq T_A \leq 70^{\circ}C \end{array} \end{array} $	•		400	800 950	μV μV
	Input Offset Voltage Drift (Note 7)	$0^{\circ}C \le T_A \le 70^{\circ}C$	•		2	5	μV/°C
l _{OS}	Input Offset Current	V _{CM} = 18V (Note 3)	•		4	8 7	nA μA
IB	Input Bias Current	V_{CM} = 18V (Note 3) SHDN or V _S = 0V, V _{CM} = 0V to 18V	••		45 35 0.1	80 60	nA μA nA
	Input Bias Current Drift	$0^{\circ}C \le T_A \le 70^{\circ}C$	•		0.06		nA/°C
	Input Noise Voltage	0.1Hz to 10Hz			0.6		μV _{P-P}
e _n	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.14		pA/√Hz
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to (V _{CC} – 1V) Common Mode, V _{CM} = 0V to 18V		0.65 0.3	1.3 1 0.5		ΜΩ GΩ MΩ
CIN	Input Capacitance				5		pF
	Input Voltage Range		•	0		18	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = 0V$ to $V_{CC} - 1V$ $V_{CM} = 0V$ to 18V (Note 6)	•	90 68	100 80		dB dB
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	90	100		dB
A _{VOL}	Large-Signal Voltage Gain	$V_{S} = 3V, V_{0} = 500mV$ to 2.5V, $R_{L} = 10k$ $V_{S} = 3V, 0^{\circ}C \le T_{A} \le 70^{\circ}C$	•	200 133	1500		V/mV V/mV
		$V_S = 5V$, $V_0 = 500mV$ to 4.5V, $R_L = 10k$ $V_S = 5V$, $0^\circ C \le T_A \le 70^\circ C$	•	400 250	1500		V/mV V/mV



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ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = 3V, 0V; V_S = 5V, 0V, V_{CM} = V_{OUT} = half supply, for the 6-lead part V_{PIN5} = 0V, pulse power tested unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 5mA$ $V_{S} = 5V$, $I_{SINK} = 10mA$	•		3 200 330	8 400 600	mV mV mV
V _{OH}	Output Voltage Swing HIGH	$V_{S} = 3V$, No Load $V_{S} = 3V$, I _{SOURCE} = 5mA	•	2.91 2.6	2.94 2.8		V V
		$V_S = 5V$, No Load $V_S = 5V$, I _{SOURCE} = 10mA	•	4.91 4.5	4.94 4.74		V V
I _{SC}	Short-Circuit Current (Note 2)	$V_S = 3V$, Short to GND $V_S = 3V$, Short to V_{CC}		5 15	10 30		mA mA
		$V_S = 5V$, Short to GND $V_S = 5V$, Short to V_{CC}		15 20	30 40		mA mA
	Minimum Supply Voltage		•		2.5	2.7	V
	Reverse Supply Voltage	I _S = -100μA		18			V
I _S	Supply Current (Note 4)		•		210	300 350	μΑ μΑ
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 8)	•		5	18	μA
I _{SHDN}	Shutdown Pin Current	$V_{PIN5} = 0.3V$, No load (Note 8) $V_{PIN5} = 2V$, No Load (Note 8) $V_{PIN5} = 5V$, No Load (Note 8)	•		0.5 2 5	8	nA μA μA
	Shutdown Output Leakage Current	V _{PIN5} = 2V, No Load (Note 8)	•		0.05	1	μA
	Maximum Shutdown Pin Current	V _{PIN5} = 18V, No Load (Note 8)			10	30	μA
VL	Shutdown Pin Input Low Voltage	(Note 8)				0.3	V
V _H	Shutdown Pin Input High Voltage	(Note 8)	•	2			V
t _{ON}	Turn-On Time	$V_{PIN5} = 5V$ to 0V, $R_L = 10k$ (Note 8)			25		μs
t _{OFF}	Turn-Off Time	V _{PIN5} = 0V to 5V, R _L = 10k (Note 8)			3		μs
GBW	Gain Bandwidth Product (Note 3)	$ \begin{array}{l} f = 5 kHz \\ 0^\circ C \leq T_A \leq 70^\circ C \end{array} $	•	750 600	1250		kHz kHz
SR	Slew Rate (Note 5)	$ \begin{array}{l} A_V = -1, \ R_L = \infty \\ 0^\circ C \leq T_A \leq 70^\circ C \end{array} \end{array} $	•	0.24 0.21	0.42		V/μs V/μs
FPBW	Full-Power Bandwidth (Note 9)	V _{OUT} = 2V _{P-P}			66		kHz
ts	Settling Time	$V_S = 5V, \Delta V_{OUT} = 2V$ to 0.1%, $A_V = -1$			12		μs
THD	Distortion	$V_{S} = 3V, V_{0} = 2V_{P-P}, A_{V} = 1, R_{L} = 10k, f = 1kHz$			0.001		%

V_S = $\pm 5V,~V_{CM}$ = 0V, V_{OUT} = 0V, for the 6-lead part V_{SHDN} = V^-

V _{OS}	Input Offset Voltage	$ \begin{array}{l} T_A = 25^\circ C \\ 0^\circ C \leq T_A \leq 70^\circ C \end{array} $	•	500	900 1050	μV μV
	Input Offset Voltage Drift (Note 7)	$0^{\circ}C \le T_A \le 70^{\circ}C$	•	2	5	μV/°C
l _{os}	Input Offset Current		•	4	8	nA
I _B	Input Bias Current		•	40	80	nA
	Input Bias Current Drift	$0^{\circ}C \le T_A \le 70^{\circ}C$	•	0.06		nA/°C
	Input Noise Voltage	0.1Hz to 10Hz		1		μV _{P-P}
en	Input Noise Voltage Density	f = 1kHz		20		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz		0.14		pA/√Hz



ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = ±5V, V_{CM} = 0V, V_{OUT} = 0V, for the 6-lead part V_{SHDN} = V⁻, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = -5V to 13V	•	0.65 0.3	1.3 0.5		ΜΩ ΜΩ
CIN	Input Capacitance				5		pF
	Input Voltage Range		•	-5		13	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -5V$ to 13V	•	68	80		dB
A _{VOL}	Large-Signal Voltage Gain	$ V_0 = \pm 4V, \ R_L = 10k \\ 0^\circ C \le T_A \le 70^\circ C $	•	70 50	160		V/mV V/mV
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 5mA I _{SINK} = 10mA	•		-4.997 -4.8 -4.67	-4.992 -4.6 -4.4	V V V
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 5mA I _{SOURCE} = 10mA	•	4.91 4.6 4.5	4.94 4.8 4.74		V V V
I _{SC}	Short-Circuit Current (Note 2)	Short to GND $0^{\circ}C \le T_A \le 70^{\circ}C$	•	18 15	30		mA mA
PSRR	Power Supply Rejection Ratio	V _S = ±1.5V to ±9V	•	90	100		dB
I _S	Supply Current		•		230	325 375	μΑ μΑ
	Supply Current, SHDN	$V_{PIN5} = -3V, V_S = \pm 5V, No Load (Note 8)$	•		6	20	μA
I _{SHDN}	Shutdown Pin Current	V_{PIN5} = -4.7V, V_S = $\pm 5V,$ No load (Note 8) V_{PIN5} = -3V, V_S = $\pm 5V,$ No Load (Note 8)	•		0.5 2	8	nA μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 9V, V_{S} = \pm 9V$ (Note 8)	•		10	30	μA
	Shutdown Output Leakage Current	$V_{PIN5} = -7V$, $V_S = \pm 9V$, No Load (Note 8)			0.05	1	μA
VL	Shutdown Pin Input Low Voltage	$V_{\rm S} = \pm 5V$ (Note 8)	•			-4.7	V
V _H	Shutdown Pin Input High Voltage	$V_{\rm S} = \pm 5V$ (Note 8)		-2.8			V
t _{ON}	Turn-On Time	$V_{PIN5} = 0V$ to $-5V$, $R_L = 10k$ (Note 8)			25		μs
t _{OFF}	Turn-Off Time	$V_{PIN5} = -5V$ to 0V, $R_L = 10k$ (Note 8)	•		3		μs
GBW	Gain Bandwidth Product	$ f = 5 kHz 0^\circ C \le T_A \le 70^\circ C $	•	800 700	1300		kHz kHz
SR	Slew Rate	A_V = –1, R_L = $\infty,$ V_0 = ±4V, Measured at V_0 = ±2V $0^\circ C$ $\leq T_A \leq 70^\circ C$	•	0.26 0.23	0.45		V/μs V/μs
FPBW	Full-Power Bandwidth (Note 9)	$V_{OUT} = 8V_{P-P}$			18		kHz
t _S	Settling Time	$\Delta V_{OUT} = 4V$ to 0.1%, $A_V = 1$			10		μs

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 3: $V_S = 5V$ limits are guaranteed by correlation to $V_S = 3V$ and $V_S = \pm 5V$ or $V_S = \pm 9V$ tests.

Note 4: $V_S = 3V$ limits are guaranteed by correlation to $V_S = 5V$ and $V_S = \pm 5V$ or $V_S = \pm 9V$ tests.

Note 5: Guaranteed by correlation to slew rate at V_S = ± 5 V, and GBW at V_S = 3V and V_S = ± 5 V tests.

Note 6: This specification implies a typical input offset voltage of 1.8mV at $V_{CM} = 18V$ and a maximum input offset voltage of 7.2mV at $V_{CM} = 18V$.

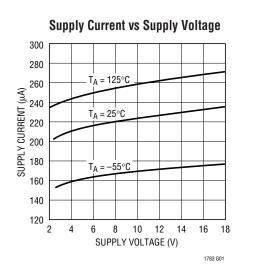
Note 7: This parameter is not 100% tested.

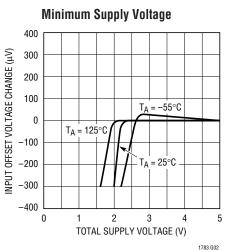
Note 8: Specifications apply to 6-lead SOT-23 with shutdown.

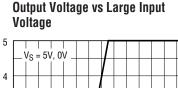
Note 9: Full-power bandwidth is calculated from the slew rate. FPBW = $SR/2\pi V_P$.

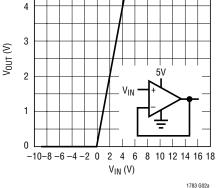
Note 10: The LT1783 is guaranteed functional over the operating temperature range -40° C to 85° C.



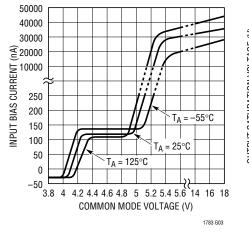




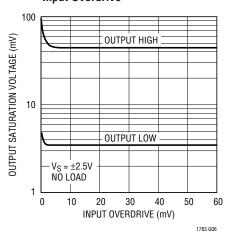




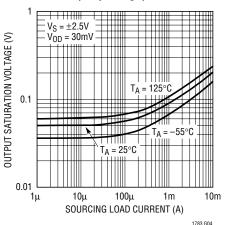
Input Bias Current vs Common Mode Voltage



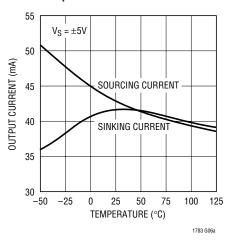
Output Saturation Voltage vs Input Overdrive



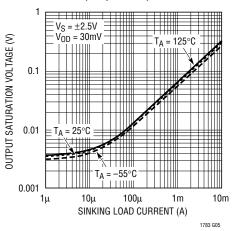
Output Saturation Voltage vs Load Current (Output High)



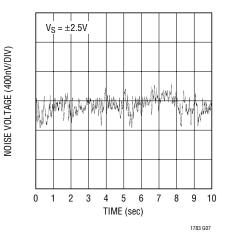
Output Short-Circuit Current vs Temperature



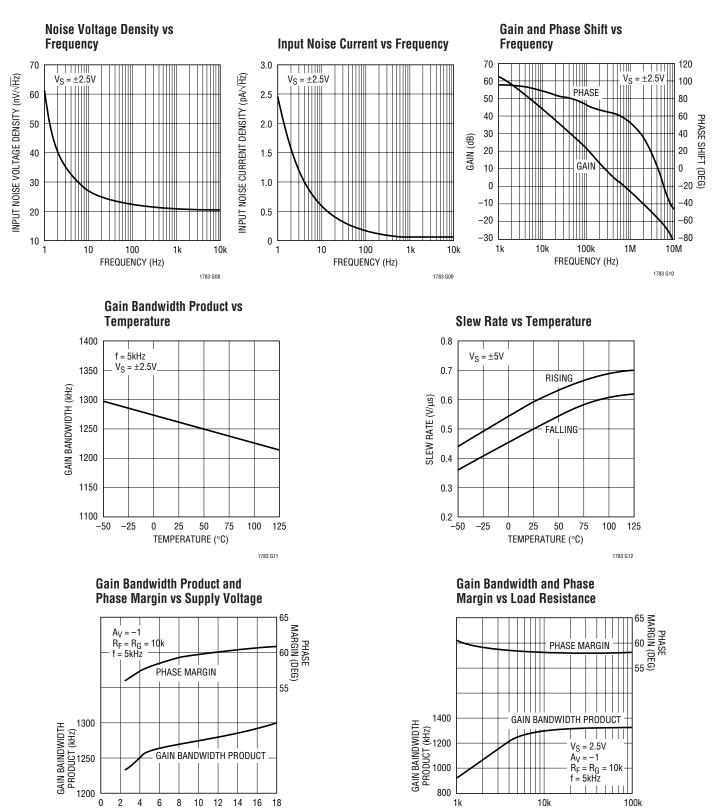
Output Saturation Voltage vs Load Current (Output Low)



0.1Hz to 10Hz Noise Voltage



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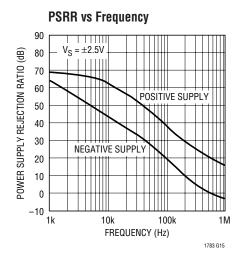
TOTAL SUPPLY VOLTAGE (V)

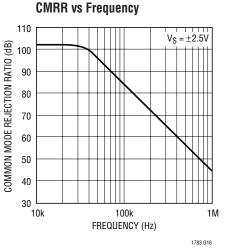
1783 G13



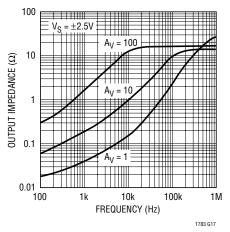
1783 G14

LOAD RESISTANCE (Ω)

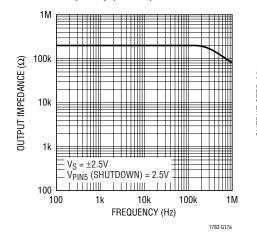




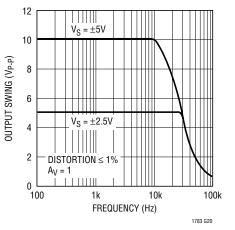
Output Impedance vs Frequency



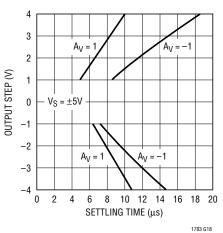
Disabled Output Impedance vs Frequency (Note 8)



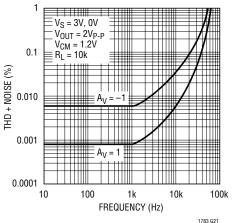
Undistorted Output Swing vs Frequency



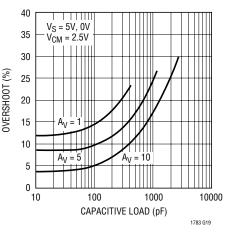
Settling Time to 0.1% vs Output Step



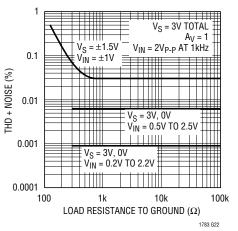
Total Harmonic Distortion + Noise vs Frequency



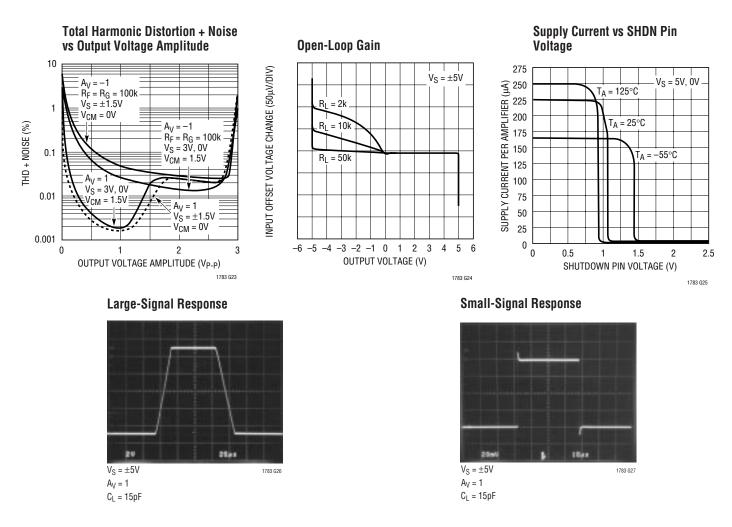
Capacitive Load Handling Overshoot vs Capacitive Load



Total Harmonic Distortion + Noise vs Load Resistance







APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1783 should be bypassed with a small capacitor (typically 0.1μ F) within an inch of the pin. When driving heavy loads, an additional 4.7μ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1783 is protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is less than 1nA.

Inputs

The LT1783 has two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V⁺, the PNP input stage is active and the input bias current is typically -40nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the

APPLICATIONS INFORMATION

input bias current is typically 80nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V⁺. The input offset voltage of the NPN stage is untrimmed and is typically 1.8mV.

A Schottky diode in the collector of the input transistors, along with special geometries for these NPN transistors, allow the LT1783 to operate with either or both of its inputs above V⁺. At about 0.3V above V⁺, the NPN input transistor is fully saturated and the input bias current is typically 30μ A at room temperature. The input offset voltage is typically 1.8mV when operating above V⁺. The LT1783 will operate with its inputs 18V above V⁻ regardless of V⁺.

The inputs are protected against excursions as much as $10V \text{ below V}^-$ by an internal 1k resistor in series with each input and a diode from the input to the negative supply. The input stage of the LT1783 incorporates phase reversal protection to prevent the output from phase reversing for inputs up to 9V below V⁻. There are no clamping diodes between the inputs and the maximum differential input voltage is 18V.

Output

The output of the LT1783 can swing to within 60mV of the positive rail with no load and within 3mV of the negative rail with no load. When monitoring input voltages within 60mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1783 can sink and source over 30mA at \pm 5V supplies, sourcing current is reduced to 10mA at 3V total supplies as noted in the Electrical Characteristics.

The LT1783 is internally compensated to drive at least 400pF of capacitance under any output loading conditions. A 0.22μ F capacitor in series with a 150 Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 10,000pF, at all output currents.

Distortion

There are two main contributors to distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current, and distortion caused by nonlinear common mode rejection. If the op amp is operating inverting, there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V⁺), the CMRR is very good, typically 100dB. When the LT1783 switches between input stages, there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion but has no effect on the input stage transition distortion. For lowest distortion, the LT1783 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and $(V^+ - 0.8V)$. See the Typical Performance Characteristics curves, "Total Harmonic Distortion + Noise vs Output Voltage Amplitude."

Gain

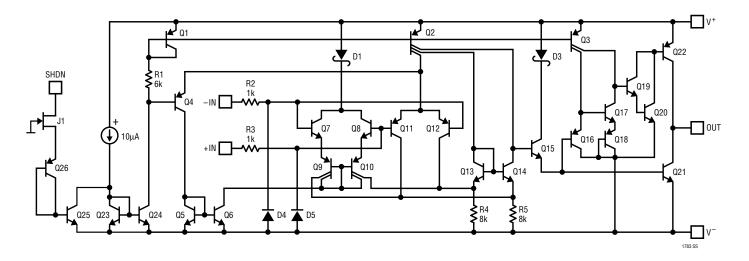
The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of open-loop gain for various loads shows the details.

Shutdown

The 6-lead part includes a shutdown feature that disables the part, reducing quiescent current and making the output high impedance. The part can be shut down by bringing the SHDN pin 1.2V or more above V⁻. When shut down, the supply current is about 5µA and the output leakage current is less than 1µA (V⁻ \leq V_{OUT} \leq V⁺). In normal operation, the SHDN pin can be tied to V⁻ or left floating. See the Typical Performance Characteristics curves, "Supply Current vs Shutdown Voltage."



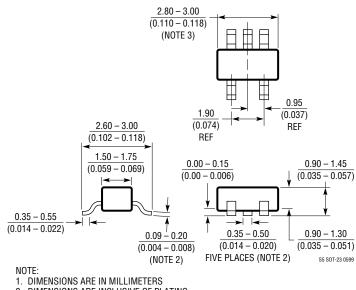
SIMPLIFIED SCHEMATIC



PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

S5 Package 5-Lead Plastic SOT-23 (LTC DWG # 05-08-1633)



2. DIMENSIONS ARE INCLUSIVE OF PLATING

3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR

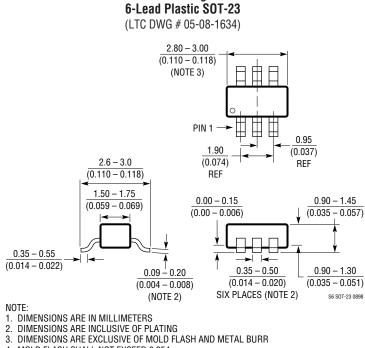
4. MOLD FLASH SHALL NOT EXCEED 0.254mm

5. PACKAGE EIAJ REFERENCE IS SC-74A (EIAJ)

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PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.



S6 Package

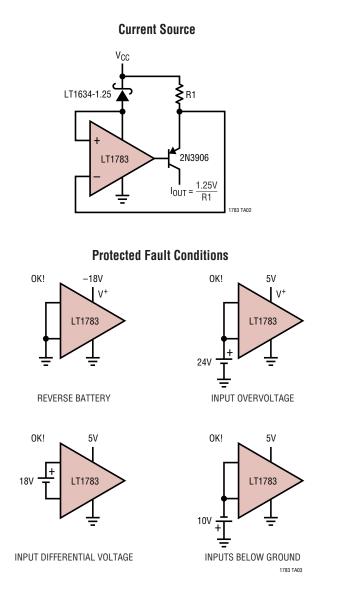
4. MOLD FLASH SHALL NOT EXCEED 0.254mm

5. PACKAGE EIAJ REFERENCE IS SC-74A (EIAJ)



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TYPICAL APPLICATIONS



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS		
LT1782	Micropower, Over-The-Top SOT-23 Rail-to-Rail Input and Output Op Amp	SOT-23 Package, Micropower 40µA per Amplifier, Rail-to-Rail Input and Output , 200kHz GBW		
LT1490/LT1491	Dual/Quad Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: –0.4V to 44V, Micropower 50µA pe Amplifier, Rail-to-Rail Input and Output , 200kHz GBW		
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	$55\mu A$ Supply Current, V_{CM} Extends 44V Above V_{EE} , Independent of $V_{CC},$ MSOP Package, Shutdown Function		
LT1638/LT1639	Dual/Quad, 1.2MHz, 0.4V/µs, Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	170µA Supply Current, Single Supply Input Range: –0.4V to 44V, Rail-to-Rail Input and Output		

